

FORM PTO-1449 (SUBSTITUTE)

Attorney Docket No.:  
GR 96 P 8091 P

Applic. No.  
09/283,907

U.S. DEPARTMENT OF COMMERCE  
PATENT AND TRADEMARK OFFICE

INFORMATION DISCLOSURE  
STATEMENT BY APPLICANT  
(37 CFR 1.98(b))

Applicant

Michael Kelly et al.

Filing Date  
April 1, 1999

Group Art Unit  
2823



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U.S. PATENT DOCUMENTS

EXAMINER INITIALS	PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
<i>AS</i>	<del>A 4,846,931</del>	<del>07/11/89</del>	<del>Gmitter et al.</del>			
<i>AS</i>	<del>B 5,465,009</del>	<del>11/02/93</del>	<del>Drabik et al.</del>			
C						
D						
E						
F						
G						
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I						

FOREIGN PATENT DOCUMENT

	DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES / NO
J						
K						
L						
M						
N						

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

O	
P	

EXAMINER

DATE CONSIDERED

*William D. - lCh* *April 16, 2002*

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.



SHEET 1 OF 4

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APRIL 1, 1999

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EXAMINER INITIALS		PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
	A	4,448,636	05/84	Baber	—	—	
	B	4,883,561	11/89	Gmitter et al.	—	—	
	C						
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## FOREIGN PATENT DOCUMENT

		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL YES	NO
	J	3508469A1	09/86	Germany	—	—		X
	K	0718885A2	06/86	Europe	—	—		X
	L							
	M							
	N							

## OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

	"Optical patterning of GaN films", M.K. Kelly et al., Appl. Phys. Lett. 69 (12), September 16, 1996, pp. 1749-1751
	"Extreme selectivity in the lift-off of epitaxial GaAs films", Eli Yablonovitch et al., Appl. Phys. Lett. 51 (26), December 28, 1987, pp. 2222-2224

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SHEET 2 OF 4

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EXAMINER INITIALS		PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
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	B						
	C						
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## FOREIGN PATENT DOCUMENT

		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES   NO
	J						
	K						
	L						
	M						
	N						

## OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

	"On the Thermal Decomposition of GaN in Vacuum", R. Groh et al., pp. 353-357
	"Few Characteristics of Epitaxial GaN-Etching and Thermal Decomposition", Yasua Morimoto, J. Electrochem. Soc.: Solid-State Science and Technology, October 1974, pp. 1383-1384
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